



FUKUCOM COMPANY LTD.

福 靈 有 限 公 司

FLAT P, 3/F., EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD,
KWUN TONG, KOWLOON, HONG KONG.

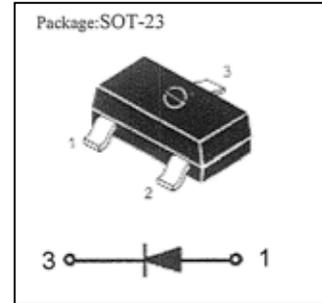
TEL: 852-2790 0314 FAX: 852-2790 0206

BAS16LT1

Dual Switching Diode

Fast Switching Speed

High Conductance



Absolute Maximum Ratings Ta=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|---------------------|-------------------------------------|----------|-------|
| V _{RM} | Non-Repetitive Peak Reverse Voltage | 100 | V |
| V _{RRM} | Peak Repetitive Reverse Voltage | 75 | V |
| V _{RWM} | Working Peak Reverse Voltage DC | | |
| V _R | Blocking Voltage | | |
| V _{R(RMS)} | RMS Reverse Voltage | 53 | V |
| I _F | Continuous Forward Current | 200 | mA |
| I _{FM} | Peak Forward Surge Current | 500 | mA |
| P _{tot} | Power Dissipation | 350 | MW |
| | Derate Above 25°C | 2.8 | mW/°C |
| T _j | Junction Temperature | 150 | °C |
| T _s | Storage Temperature range | -65~+150 | °C |

Electrical Characteristics Ta=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|-----------------|-----------------------|--|------|------|------|-------|
| V _F | Forward Voltage | I _F = 1mA | | | 715 | mV |
| | | I _F = 10mA | | | 855 | |
| | | I _F = 50mA | | | 1.0 | |
| | | I _F = 150mA | | | 1.25 | |
| I _R | Leakage Current | V _R = 75V | | | 1.0 | uA |
| | | V _R = 75V T _j =150°C | | | 50 | |
| | | V _R = 25V T _j =150°C | | | 30 | |
| C _j | Capacitance | V _F = 0V, f=1MHz | | | 2 | pF |
| T _{rr} | Reverse Recovery Time | I _F =10mA, I _{RR} =1.0mA V _F =6.0V, R _L =100Ω | | | 6 | ns |

Note: Diode on Ceramic Substrate 10mm x 8.0mm x 0.7mm

Marking : A6



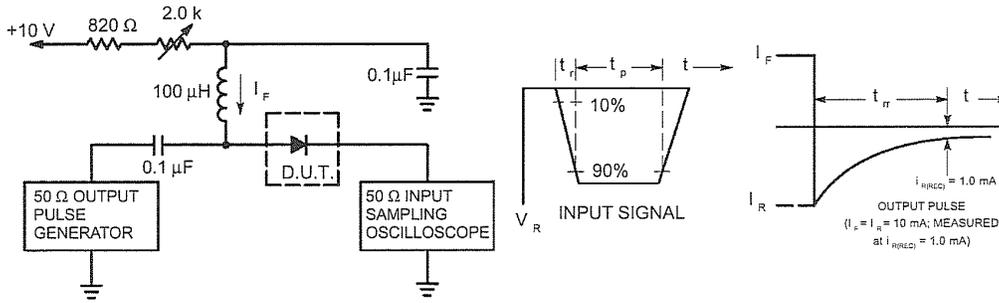
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- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10 mA.
- 2. Input pulse is adjusted so $I_{R(\text{peak})}$ is equal to 10 mA.
- 3. $t_p \gg t_r$

Figure 1. Recovery Time Equivalent Test Circuit

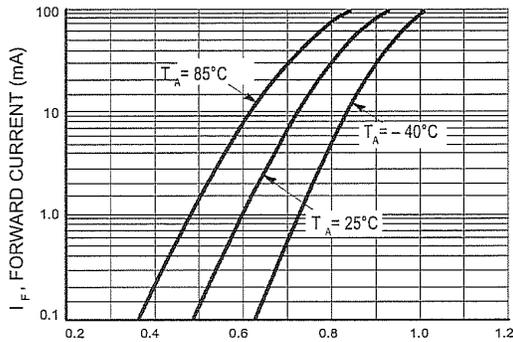


Figure 2. Forward Voltage

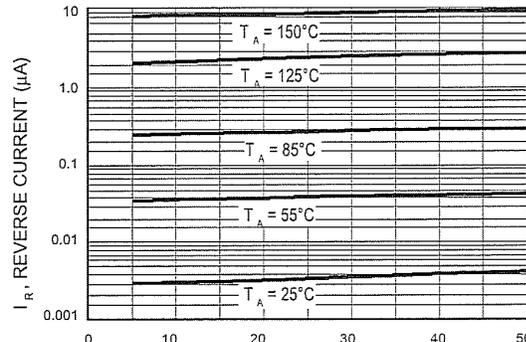


Figure 3. Leakage Current

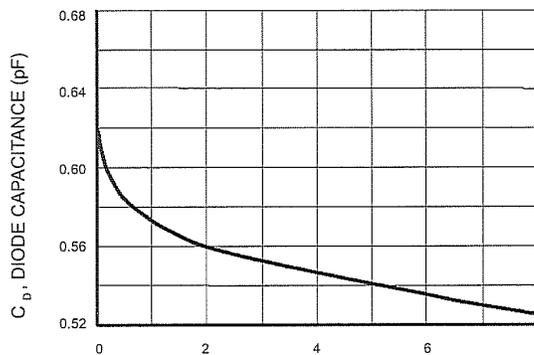


Figure 4. Capacitance